Record Nr. UNINA9910139499203321 Silicon nanocrystals [[electronic resource]]: fundamentals, synthesis **Titolo** and applications / / edited by Lorenzo Pavesi and Rasit Turan Pubbl/distr/stampa Hoboken, NJ,: Wiley-Blackwell, 2010 **ISBN** 1-282-48274-2 9786612482748 3-527-62995-5 3-527-62996-3 Descrizione fisica 1 online resource (651 p.) Altri autori (Persone) PavesiLorenzo **TuranRasit** 661.0683 Disciplina 661.0683 22 Soggetti Nanosilicon Silicon crystals Electronic books. Lingua di pubblicazione Inglese **Formato** Materiale a stampa Livello bibliografico Monografia Description based upon print version of record. Note generali Nota di bibliografia Includes bibliographical references and index. Nota di contenuto Silicon Nanocrystals: Fundamentals, Synthesis and Applications; Contents: List of Contributors: 1 Introduction: References: 2 Electronic and Optical Properties of Silicon Nanocrystals; 2.1 Introduction; 2.2 Ab Initio Calculation for Small Nanocrystals; 2.2.1 Hydrogenated Silicon Nanocrystals; 2.2.2 Oxidized Silicon Nanocrystals; 2.2.3 Doped Silicon Nanocrystals; 2.2.3.1 Single-Doped Silicon Nanocrystals; 2.2.3.2 Codoped Silicon Nanocrystals; 2.2.4 Silicon Nanocrystals Embedded in a SiO2 Matrix; 2.3 Pseudopotential Calculations for Large Nanocrystals; 2.3.1 Effective Optical Gap 2.3.2 Radiative Lifetime 2.3.3 Linear Optical Absorption; 2.3.3.1 Interband Absorption; 2.3.3.2 Intraband Absorption; 2.3.3.3 Excited State Absorption; 2.3.4 Third-Order Nonlinear Optical Properties; 2.3.5 Quantum-Confined Stark Effect in Si Nanocrystals; References; 3 Optical Properties of Intrinsic and Shallow Impurity-Doped Silicon Nanocrystals; 3.1 Introduction; 3.2 PL Properties of Intrinsic Silicon

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## Sommario/riassunto

This unique collection of knowledge represents a comprehensive treatment of the fundamental and practical consequences of size reduction in silicon crystals. This clearly structured reference introduces readers to the optical, electrical and thermal properties of silicon nanocrystals that arise from their greatly reduced dimensions. It covers their synthesis and characterization from both chemical and physical viewpoints, including ion implantation, colloidal synthesis and vapor deposition methods. A major part of the text is devoted to applications in microelectronics as well as photonics